

● PRINTER RUSH ●
(PTO ASSISTANCE)

Application : 10/810631 Examiner : Tran GAU : 2818
From: J. Black Location: IDC FMF FDC Date: 4/22/05
Tracking #: 06072223 Week Date: 1/31/05

DOC CODE	DOC DATE	MISCELLANEOUS
<input checked="" type="checkbox"/> 1449	<u>9/21/04</u>	<input type="checkbox"/> Continuing Data
<input type="checkbox"/> IDS		<input type="checkbox"/> Foreign Priority
<input type="checkbox"/> CLM		<input type="checkbox"/> Document Legibility
<input type="checkbox"/> IIFW		<input type="checkbox"/> Fees
<input type="checkbox"/> SRFW		<input type="checkbox"/> Other
<input type="checkbox"/> DRW		
<input type="checkbox"/> OATH		
<input type="checkbox"/> 312		
<input type="checkbox"/> SPEC		

[RUSH] MESSAGE:

Sheet 1 of 5: First other document has data cut-off on right side of page.

Please resolve.

[XRUSH] RESPONSE:

Corrected

Carl Brundidge

203-684-1120

INITIALS: PS

NOTE: This form will be included as part of the official USPTO record, with the Response document coded as XRUSH.

REV 10/04

501.35478 CX22

4/29

10/8/04 (63)

SHEET 1 OF 5

FORM PTO-1449 U.S. Department of Commerce Patent and Trademark Office INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)								ATTY. DOCKET NO. 501.35478CX22	SERIAL NO. Not yet assigned
								APPLICANT MIWA, et al	FILING DATE March 29, 2004

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER								DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
		4	9	6	4	0	7	9		10/90	Devin			
		5	3	6	5	4	8	6		11/94	Schreck			
		5	4	1	2	6	0	1		5/95	Sawada et al	365	185.03	
		5	8	3	1	9	0	0		11/98	Miyamoto	365	185.03	
		5	7	4	5	4	0	9		4/98	Wong et al	365	185.03	
		5	5	5	5	2	0	4		9/96	Endoh et al	365	189.01	
		5	1	5	1	3	8	7		9/92	Brady et al	437	191	4/30/90
		5	0	8	4	4	1	7		1/92	Joshi et al	437	192	3/13/89
		5	0	5	9	5	5	4		10/91	Spinner et al	437	193	6/23/89
		6	1	7	2	3	3	8		12/92	Mehrotra et al			
		6	1	3	8	6	7	6		8/92	Madurawe			
		5	4	8	7	0	3	6		1/96	Akaogi et al	365	185.23	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER								DATE	COUNTRY	CLASS	SUBCLASS	ABSTRACT	
		YES	NO												
		5	9	1	2	1	6	9	6	7/84	Japan				XX
		4	2	3	8	1	9	6		8/92	Japan				XX
		4	5	7	2	9	4			2/92	Japan				XX

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Digest of Technical Papers, ATP 2.1: A 3.3V 128Mb Multi-level NAND Flash Memory for Mass Storage Applications, T. Jung, et al., ISSCC96/Session 2/Flash Memory/Paper TP 2.1, 1996 EEE International Solid State Circuits Conf.
	Betty Prince, "Semiconductor Memories", 1983, Wisely, 2 nd Edition, pp. 620-621.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation is considered, draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

(Form PTO-1449 [6-4])